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Scalable and sustainable production of $Ti_3C_2T_z$ MXene and fluorine recovery from wastewater through cryolite precipitation

Michael S. Carey and Michel W. Barsoum *

Treatment of HF or HCl/LiF etched $Ti_3C_2T_z$ with 0.05 M NaHCO₃ before water washing reduces the wastewater generated by 75%. When etched with HF, cryolite (Na₃AlF₆) precipitation from spent etching waste effectively removes fluorine from this waste stream, offers insight into the etching chemistry of MAX to MXene, and provides an effective analytical tool for optimization of MXene production. Additionally, washing HF etched multilayered $Ti_3C_2T_z$ with 0.05 M NaHCO₃ allows for the production of delaminated $Ti_3C_2T_z$ colloidal suspensions, which typically requires the use of TBAOH or DMSO for intercalation and subsequent delamination. $Ti_3C_2T_z$ made with HCl/LiF and washed with 0.05 M NaHCO₃ yields a colloidal suspension with a concentration of 18 mg mL⁻¹ and a film conductivity of 1150 S cm⁻¹.

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Introduction

Traditional synthesis of $Ti_3C_2T_z$ MXene, most commonly obtained by the selective etching of Al from a Ti_3AlC_2 MAX phase¹⁻³ with hydrofluoric acid, HF, requires a large amount of water to obtain a colloidal suspension of few, to single, flake $Ti_3C_2T_{z^*}$.^{3,4} Typically, the amount of water needed is at least 640 mL per gram of MXene as this water is thought to both wash away residual salts formed in the etching process, and to bring the solution pH to neutral at which point a stable colloidal MXene suspension forms. Herein we show that by modifications made to the synthesis process, we can obtain $Ti_3C_2T_z$ colloidal suspensions with 75% less water utilized in the washing procedure. The fluorine, F, in the remaining wastewater can also be recovered through the precipitation of cryolite.

While MXenes have been shown to be quite promising in terms of their performance across a wide variety of applications, their widescale production has lagged.^{5–7} One of the limiting steps at this time is the large cost of their production and the need for F in the etching medium. Additionally, the treatment of HF containing wastewater is both a major industrial and environmental concern.⁸

For MXene production to occur at industrial scales, the large amount of acidic wastewater that is currently a byproduct of its methods of production must be addressed. Furthermore, the presence of F^- in this wastewater is problematic as this treatment is quite costly and produces a large amount of industrial waste sludge that becomes difficult to dispose of due to environmental regulations.⁹ It was long believed that the main product of the selective etching of Al from Ti₃AlC₂ to yield $Ti_3C_2T_z$ is AlF₃,¹⁰ which has limited solubility in water (0.5 g/ 100 g H₂O at 25 °C).¹¹ However, Cockreham *et al.* showed that AlF₃ formation only occurs under a range of ionic strength from 8.5 to 10 M and other aluminum/fluorine complex ions are dominant outside this range.¹² It should be noted that this work explored the use of cobalt fluorides (CoF₂/CoF₃) as a source of F, and the applicability to HF or HCl/LiF etching methods has not been demonstrated.

The Ti₃AlC₂ MAX phase is known to form a protective oxide layer which is composed of Al₂O₃ and TiO₂.¹³ A product of the reaction between Al-containing species such as alumina comprising this oxide layer, or the aluminum in the MAX structure, and HF is hexafluoroaluminic acid (H_3AlF_6) .^{14,15} If H_3AlF_6 is present, then a route to recovering F from the wastewater exists through the addition of sodium cations to form sodium hexafluoroaluminate, otherwise known as cryolite, which can be readily isolated from the spent etching liquid.^{14,15} The yield of precipitated cryolite allows for the calculation of Al etching efficiency, while also being a product of commercial value. In the reaction of the Al in Ti₃AlC₂ with HF, a route for the formation of hexafluoroaluminic acid and cryolite may be as follows:

$$2Al + 6HF_{(aq)} \rightarrow 2AlF_{3(aq)} + 3H_{2(g)}$$
(1)

$$AlF_{3(aq)} + 3HF \rightarrow H_3AlF_{6(aq)}$$
(2)

$$2H_3AlF_{6(aq)} + 3Na_2CO_3 \rightarrow 2Na_3AlF_6 + 3H_2O + 3CO_{2(g)}$$
 (3)

With the typical etching procedures using HF^{16} or HCl/LiF^3 there is enough HF to fully convert AlF_3 to H_3AlF_6 . Furthermore, AlF_6^{3-} is believed to be a stable species as the ionic strength of the solution increases.^{12,17} In this reaction, the formation of

Department of Materials Science and Engineering, Drexel University Philadelphia, PA 19104, USA. E-mail: barsoumw@drexel.edu

 H_3AlF_6 may provide a driving force for the continued extraction of Al from Ti₃AlC₂, potentially explaining why HF is the only acid capable of etching the MAX phase to yield MXenes.^{5,18} The structures of hexafluoroaluminic acid and cryolite are shown in Fig. 1.

Sodium hexafluoroaluminate, Na₃AlF₆, more commonly known as cryolite, is insoluble in water, but soluble in sulfuric acid, H₂SO₄, with the evolution of HF. Synthetic cryolite finds widespread industrial use as a flux agent to dissolve alumina, Al₂O₃, in the electrolytic metal extraction process. It is also consumed in the abrasives, ceramic and glass industries.^{15,19} Many research articles and patents have appeared over the years regarding the production of cryolite, suggesting that if cryolite can be isolated and repackaged as a by-product of MXene production, the economics associated with the scale-up of MXene synthesis may be partially offset. By our calculations, assuming complete etching of Al from Ti₃AlC₂ and complete conversion to cryolite, 1.07 g may be produced from 1 g of Ti₃AlC₂. This may be an attractive method to lower the cost of wastewater treatment and produce a high purity, high value compound, while also providing a quantitative tool for the determination of etching efficiency. The feasibility of this method is supported by the work of Kumar et al. which showed that the recovery of synthetic cryolite from the treatment of synthetic HCl/HF leach liquors comprising H₃SiF₆ and H₃AlF₆ with 3 M Na_2CO_3 was 97.5%.¹⁵

In this work we demonstrate that by washing the acidified MXene sediment once with a mild solution of low-cost and environmentally benign sodium bicarbonate, BC, colloidal suspensions can be produced using 75% less deionized water than otherwise needed. This reduction in wastewater is achieved independent of the etching method (HF *vs.* HCl/LiF). By similarly treating the waste HF etching liquid with 3 M sodium carbonate, cryolite can easily be formed and precipitated, according to reaction (3), providing a useful method for the determination of Al extraction efficiency as well as providing a value-added product which effectively removes F from the waste stream.

Results & discussion

The sediments produced by this method were first investigated by XRD to ensure that etching of the MAX phase was complete, and to characterize the obtained MXene. In Fig. 2, XRD patterns of multilayer (ML) MXene obtained by normal deionized (DI)



Fig. 1 (a) Structure of hexafluoroaluminic acid, and (b) structure of cryolite, ${\sf Na}_3{\sf AlF}_6.$



Fig. 2 XRD patterns of MXene obtained by normal washing 8 times with DI (black – solid line is HF etched ML, dotted line is HCl/LiF etched delaminated films), after 1 wash with 0.05 M NaHCO₃ and 2 times with DI (red – solid line is HF etched ML, dotted line represents HCl/LiF etched delaminated films), Ti₃AlC₂ MAX phase precursor (orange), the precipitated Na₃AlF₆ (blue), and a reference profile for Na₃AlF₆ (dotted bottom red).

water washing, with 8 washes of DI (middle, black), ML MXene after 1 wash with 40 mL 0.05 M NaHCO₃ and 2 washes of DI, (top, red) and the precipitated Na₃AlF₆ from the spent etching liquid. A reference profile for Na₃AlF₆, is also presented.

It is evident from these patterns that the MXene obtained by the neutralization method is the same as the MXene obtained by the normal washing method. In fact, the HF-etched ML MXene pattern obtained after BC and DI washing appears to be cleaner than the water only washed sample, as many peaks associated with Ti₃AlC₂ in the range of ~35–45° 2θ are still present in that sample. Interestingly, the 110 peak present at ~61° 2θ is not present in the BC washed specimen, suggesting that there is a complete absence of non-basal ordering in this sample. Furthermore, the HCl/LiF, BC washed film does not display the same number of 00*l* reflections as the HCl/LiF, DI washed film.

The cryolite precipitated from the waste etching liquid matches nearly perfectly to the reference pattern (bottom red dotted lines in Fig. 2). The amount of cryolite was measured to be 0.89 g, indicating an etching efficiency of 84%. We believe that this method can prove to be an effective tool for optimizing the etching efficiency, and this value can be pushed closer to 100% by variations in etching conditions such as time, pH of solution, temperature, or reagent concentrations.

Complete washing of $Ti_3C_2T_z$ MXene (indicated by a nearneutral pH and stable supernatant after centrifugation) requires between 8 and 10 washing cycles when only washing with only DI H₂O. However after treatment with 0.05 M NaHCO₃ (regardless of HF or HCl/LiF etching method), this stability occurred within two rounds of washing, as seen in Fig. 3. Interestingly, a stable suspension is found after just the first wash (Fig. 3a). However in our washing procedure, an additional wash step was carried out that resulted in a darker, more concentrated suspension (Fig. 3b). Washing with DI H₂O only, required 640 mL. However with the incorporation of one 40 mL 0.05 M NaHCO₃ wash before subsequent DI washes, the volume of water necessary to produce a dark colloidal suspension was 160 mL per gram of Ti₃C₂T_z sediment. An SEM micrograph of the Ti₃C₂T_z filtered film after exposure to NaHCO₃ can be seen in Fig. 4a and b along with an SEM micrograph of the obtained Na₃AlF₆ in Fig. 4c.

Typically, $Ti_3C_2T_z$ produced by etching with HF, only do not yield delaminated flakes (referred to as d-Ti₃C₂T_z, to insinuate delamination) without the use of a chemical exfoliation agent such as TBAOH or DMSO.^{5,20-22} However, with our approach, a colloidal suspension was obtained after NaHCO₃ and DI water washing, and a film of d-Ti₃C₂T_z was produced by vacuum filtration of this suspension (Fig. 4a). A photograph of this colloidal suspension, and the Tyndall effect produced by the d-Ti₃C₂T_z flakes, is shown as an inset of Fig. 4a. Conductivity measurements were conducted on this film with a four-point probe, and a DC conductivity of 180 ± 10 S cm⁻¹ was measured.

A film was attempted to be produced by the DMSO assisted intercalation and delamination of HF etched, water only washed, $Ti_3C_2T_z$, however the concentration of this suspension



Fig. 3 Digital images of post-neutralization washing procedure with $NaHCO_{3}$ (a) After washing once, and (b) twice with DI water.



Fig. 4 SEM micrograph of, (a) $Ti_3C_2T_z$ film obtained after 1 wash with 40 mL 0.05 M NaHCO₃. Inset: Tyndall effect of delaminated, HF– $Ti_3C_2T_z$ colloidal suspension after 0.05 M NaHCO₃ and H₂O washing. (b) Multilayered HF– $Ti_3C_2T_z$ powders after etching and washing with NaHCO₃, demonstrating the accordion-like structure of ML- $Ti_3C_2T_z$, and (c) cryolite precipitated from the spent etching liquid. Inset in (c) is picture of obtained cryolite.

was so slow that a continuous film was unable to be obtained. Conductivity measurements were attempted on a section of this 'film' and a value of 2.25 \pm 0.05 S cm⁻¹ was measured.

Conductivity measurements were similarly conducted on HCl/LiF etched films, one washed first with 0.05 M NaHCO₃, and the other washed only with water. In the BC washed case, the colloidal suspension had a concentration of 18 mg mL⁻¹ and a film produced from this suspension had conductivity of 1150 \pm 27 S cm⁻¹ was measured, while the H₂O washed colloidal suspension had a concentration of 15.6 mg mL⁻¹ and the corresponding film had a conductivity of 1330 \pm 54 S cm⁻¹.

Conclusions

In summary, a simple yet effective method of obtaining $Ti_3C_2T_2$ MXene is presented where the isolated etched sediment is neutralized with a mild solution of sodium bicarbonate. In so doing, the pH can directly be adjusted to neutral without the need of large volumes of DI water. This drastically reduces the amount of wastewater generated, specifically from 640 mL g $^{-1}$ to 160 mL g $^{-1}$, a reduction of 75%. This holds for both HF only and HCl/LiF etched Ti₃C₂T_z. Furthermore, when etched with HF, delaminated films of Ti₃C₂T_z could be produced, provided they were treated with 0.05 M NaHCO₃ before washing with deionized water. Furthermore, films produced by etching with HCl/LiF and then washed once with 0.05 M NaHCO₃, followed by two washes with deionized water resulted in a colloidal suspension with a concentration of 18 mg mL⁻¹ Filtered films made from this suspension had a conductivity of 1,150 \pm 27 S cm⁻¹. Additionally, cryolite (Na₃AlF₆) can be formed from this process, which indicates that the etching media used for the extraction of Al from Ti₃AlC₂ must contain hexafluoroaluminic acid, H₃AlF₆. This provides insight into the chemistry of the etching reaction and allows for the recovery of fluorine from the spent etching liquid. The cryolite obtained from this neutralization can be precipitated by treatment with sodium carbonate, further offsetting the cost of MXene production, and providing a quantitative tool for calculating etching efficiency which would allow for the optimization of the etching parameters such as time, temperature, pH and reagent concentrations.

Materials & methods

The experimental approach in this work is largely separated into two segments which are focused on: (1) neutralization of the MXene sediment to obtain high quality $Ti_3C_2T_z$ MLs with less water, and (2) precipitation of cryolite from the spent etching waste.

Two etching methods are explored in this work. Namely, the use of HF acid only as well as the method first reported by Ghidiu *et al.* utilizing hydrochloric acid and lithium fluoride to produce HF *in situ.*² The latter method is more widely adopted due to the improved handling safety and ability to directly yield delaminated suspensions. However, when considering the precipitation of cryolite through neutralization of the spent etching liquid, the HF only method is a much cleaner system, as there are fewer ionic species present. For the purposes of this work, we demonstrate that cryolite, Na₃AlF₆, can be precipitated from the spent etching media obtained from the HF-only method.

The neutralization of the MXene sediment with 40 mL 0.05 M NaHCO₃ is applicable to both methods of MXene production. Given that the HCl/LiF method is more widely adopted by those that work with MXene, we felt it was important

to demonstrate the effectiveness of this washing procedure when working with HCl/LiF etched MXene.

HF etching of Ti_3AlC_2 to produce HF- $Ti_3C_2T_z$

MXene etched by HF acid only, (henceforth referred to as HF– $Ti_3C_2T_z$) was obtained by etching 1 g of Ti_3AlC_2 MAX phase in 10 mL of 10% HF for 24 h at RT.

Sodium bicarbonate washing of HF-Ti₃C₂T_z

After the etching period, the HF–Ti₃C₂T_z ML sediment is isolated from the etching liquid through centrifugation. The spent liquid portion is set aside and used for cryolite precipitation. After separation, the sediment in each centrifuge tube (0.5 g per tube) was treated with 40 mL of 0.05 M NaHCO₃ so that the pH was adjusted to 7.0. After the initial wash with 0.05 M NaHCO₃, the sediment was washed two times with 40 mL of DI water.

Delamination of NaHCO3 washed HF-Ti3C2Tz

20 mL of DI water was added to the sediment obtained after washing with 0.05 M NaHCO₃ and DI water, which was then bath sonicated for 1 h under argon flow. After sonication, the colloidal suspension was isolated by centrifugation at 5000 rpm for 10 minutes. This suspension was then filtered to obtain a film.

HF-etched, H_2O washed $Ti_3C_2T_z$

For comparison to the NaHCO₃ method, a separate 1 g batch of HF-Ti₃C₂T_z was washed only with DI water. To produce a film of the HF-Ti₃C₂T_z washed only with water, 12 mL of dimethyl sulfoxide (DMSO) was added to the washed sediment and allowed to mix for 24 h at room temperature (RT). After mixing, the DMSO was separated by centrifugation at 3500 rpm for 5 minutes. 20 mL of DI H₂O was added to the DMSO intercalated sediment, and bath sonicated for 1 h under flowing argon. After sonication, the colloidal suspension was isolated by centrifugation at 5000 rpm for 10 minutes. This suspension was then filtered to obtain a film.

Precipitation of cryolite from HF-Ti₃C₂T_z etching media

Cryolite was precipitated by adding 3 M Na_2CO_3 to the isolated etching liquid until a pH of 4.0. This solution was then kept in a 55 °C oil bath for 1 h, after which the gelatinous liquid was vacuum filtered over a Celgard polypropylene membrane where a white crystalline solid was formed.

HCl/LiF-etched Ti₃C₂T_z

To demonstrate the applicability of this method to the more widely used method first reported by Ghidiu *et al.*,² two grams of $Ti_3C_2T_z$ were prepared by etching two grams of Ti_3AlC_2 in 20 mL of 12 M HCl along with two grams of lithium fluoride. This mixture was allowed to mix at 35 °C for 48 h at 300 rpm.

After etching, the contents of the etching bottle were split equally into four centrifuge tubes so that 0.5 g of sediment was in each centrifuge tube. Two of the tubes were washed only with deionized water, while the other two were first washed with $40~\mathrm{mL}$ of 0.05 M NaHCO3, followed by two washes with deionized water.

After the washing period, the contents of the tubes were combined so that roughly 1 g of each separately washed powders of $Ti_3C_2T_z$ were in each tube. 20 mL of DI H₂O was added to each tube, and these mixtures were bath sonicated for 1 h under flowing argon. After sonication, the colloidal suspensions were collected by centrifugation at 5000 rpm for 10 minutes. These colloidal suspensions were filtered into films by vacuum filtration.

Author contributions

M. C. conducted all experiments and wrote the manuscript along with M. W. B. who oversaw the project.

Conflicts of interest

There are no conflicts to declare.

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